WINSOURCE ELECTRONICS

THE DATASHEET OF

MBR860S

Technical Data
Data Sheet N0029, Rev. B

RoHS HF

MBR860S SCHOTTKY RECTIFIER

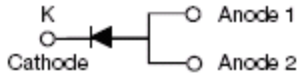


TO-277B

Features

- Designed as Bypass Diodes for Solar Panels
- High Forward Surge Capability
- Ultra Low Forward Voltage Drop
- Excellent High Temperature Stability
- Terminals finish: 100% Pure Tin
- This is a Halogen Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	-	60	V
Average Rectified Forward Current	$I_{F(AV)}$	50% duty cycle @Tc=80°C, rectangular wave form	8	A
Peak One Cycle Non-Repetitive Surge Current	I_{FSM}	8.3ms, Half Sine pulse, Tc=25°C	150	A

Electrical Characteristics:

Characteristics	Symbol	Condition	Typ.	Max.	Units
Forward Voltage Drop *	V_{F1}	@ 8A, Pulse, T_J = 25 °C	0.63	0.65	V
	V_{F2}	@ 8A, Pulse, T_J = 125 °C	0.58	0.60	V
Reverse Current*	I_{R1}	@V_R = rated V_R T_J = 25 °C	0.008	1.0	mA
	I_{R2}	@V_R = rated V_R T_J = 125°C	3	20	mA
Junction Capacitance	Cj	@V_R = 5.0 V, Tc=25℃ f_{SIG} = 1MHz	260	400	pF

* Pulse width < 300 µs, duty cycle < 2%

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Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T_J	-	-55 to +150	°C
Storage Temperature	T_{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{\theta JC}$	-	3.5	°C/W
Typical Thermal Resistance Junction to Ambient	$R_{\theta JA}$		70	°C/W
Approximate Weight	wt	-	0.08	g

Ratings and Characteristics Curves

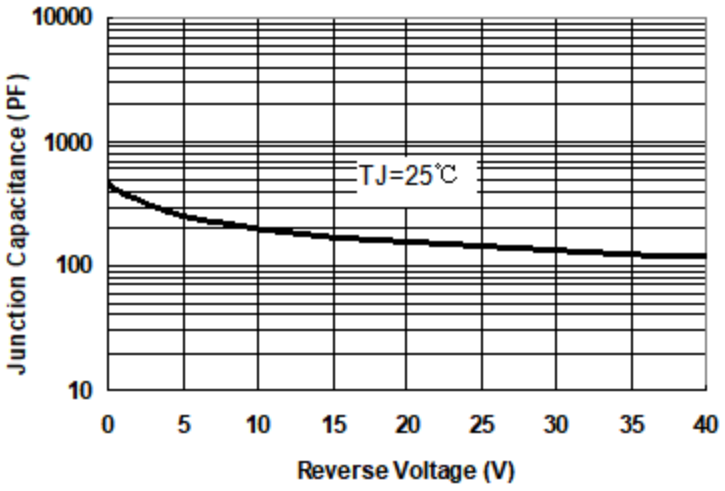


Fig.1-Typical Junction Capacitance

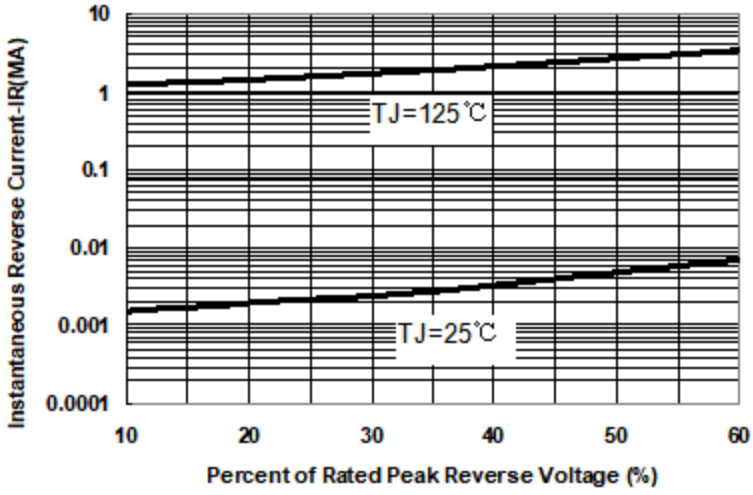


Fig.2-Typical Reverse Characteristics

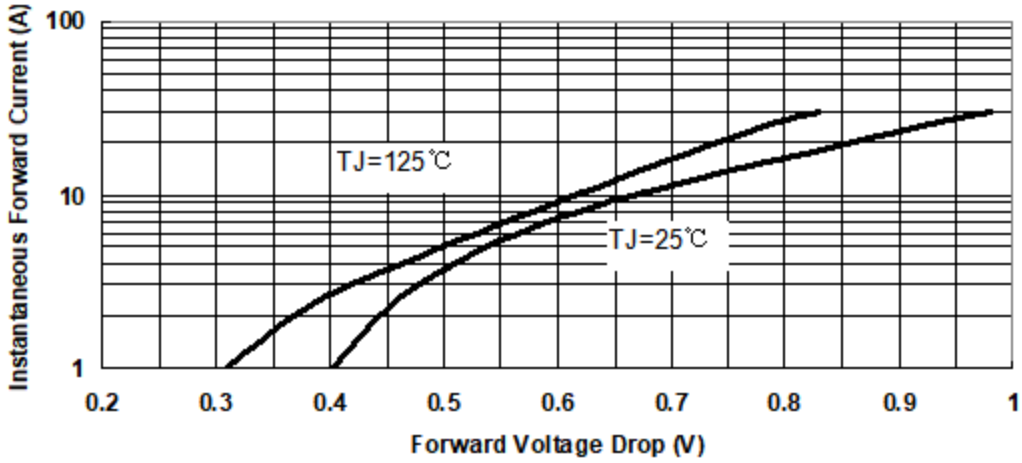
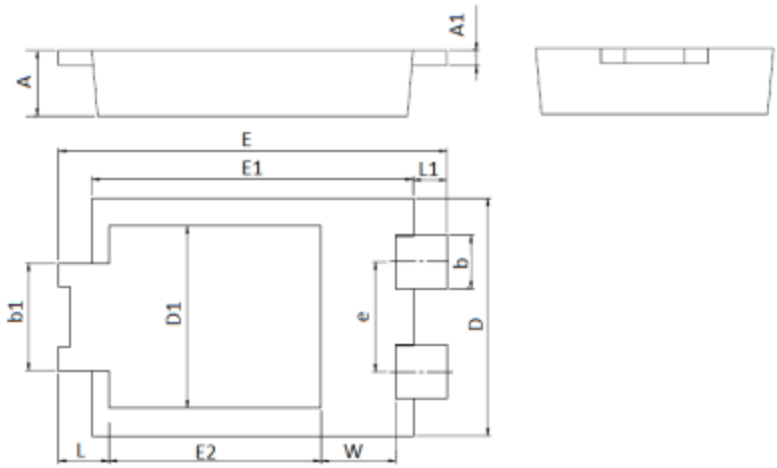


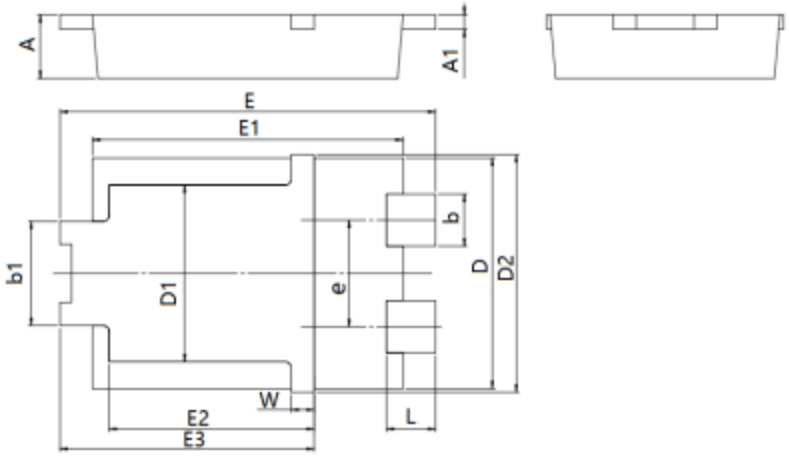
Fig.3-Typical Instantaneous Forward Voltage Characteristics

Mechanical Dimensions TO-277B



SYMBOL	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	0.95	1.25	0.037	0.049
A1	0.20	0.30	0.008	0.012
b	0.85	0.95	0.033	0.037
b1	1.70	1.90	0.067	0.075
D	3.88	4.08	0.153	0.161
D1	2.90	3.20	0.114	0.126
e	1.74	1.94	0.069	0.076
E	6.30	6.70	0.248	0.264
E1	5.28	5.48	0.208	0.216
E2	3.40	3.70	0.134	0.146
L	0.70	1.00	0.028	0.039
L1	0.41	0.71	0.016	0.028
W	1.10	1.40	0.043	0.055

Mechanical Dimensions TO-277B(New)



SYMBOL	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	0.95	1.25	0.037	0.049
A1	0.20	0.30	0.008	0.012
b	0.85	0.95	0.033	0.037
b1	1.70	1.90	0.067	0.075
D	3.88	4.08	0.153	0.161
D1	2.90	3.20	0.114	0.126
D2	4.25	-	0.167	-
e	1.74	1.94	0.069	0.076
E	6.30	6.70	0.248	0.264
E1	5.28	5.48	0.208	0.216
E2	3.40	3.70	0.134	0.146
E3	4.20	4.60	0.165	0.181
L	0.65	1.05	0.025	0.041
W	0.25	0.55	0.010	0.022

Notes: New Mechanical Dimensions is performed from date code 2236X.

MBR860S

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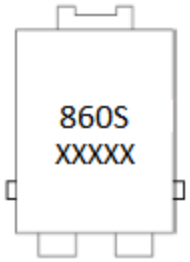
Ordering Information

Device	Package	Shipping
MBR860S	TO-277B(Pb-Free)	5000pcs/ reel
MBR860STR	TO-277B(Pb-Free)	5000pcs/ reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram

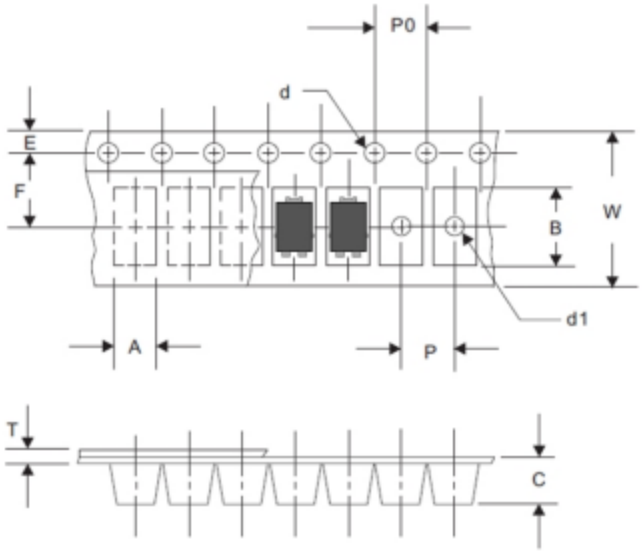


Where XXXXX is YYWWL

8 = Forward Current (8A)
60 = Reverse Voltage (60V)
S = Package type
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin
Epoxy resin UL:94V-0

Carrier Tape Specification TO-277B



SYMBOL	Millimeters	
	Min.	Max.
A	4.28	4.48
B	6.80	7.10
C	1.30	1.50
d	1.40	1.60
d1	-	1.50
E	1.65	1.85
F	5.40	5.60
P	7.90	8.10
P0	3.90	4.10
T	0.24	0.44
W	11.70	12.30

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